NSN 5961-01-418-5362

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-418-5362 **Inclosure Material:** Metal **Overall Length:** 1.020 inches **Overall Height:** Between 0.147 inches and 0.167 inches Overall Width: Between 0.815 inches and 0.825 inches **End Application:** An/upm-155 **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Source **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 drain to gate voltage and 60.0 drain to source voltage and 20.0 gate to source voltage **Power Rating Per Characteristic:** 14.4 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Test Data Document:** 57057-8880200052 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 ribbon and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No